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S 4811

B.E./B.Tech. DEGREE EXAMINATION, NOVEMBER/DECEMBER 2007.

Annual Pattern — First Year

Mechatronics Engineering

EC 1X12 — ELECTRONICS DEVICES AND CIRCUIT

(Regulation 2004)

Time : Three hours

Maximum : 100 marks

Answer ALL questions.

PART A — (10 × 2 = 20 marks)

1. State Superposition Theorem.
2. Find the z parameters of a two-port network for which
 $V_1 = V_2 + I_2$ and $I_1 = I_2 + V_1 + V_2$.
3. How does the energy band structure of a semiconductor differ from that of a conductor and an insulator?
4. Compare JFET with BJT.
5. Define Peak Inverse Voltage (PIV) of a rectifier.
6. A 10 V zener diode is used to regulate the voltage across a variable load resistor. The input voltage varies between 13 V and 16 V and the load current varies between 10 and 85 mA. The minimum zener current is 15 mA. Calculate the value of the series resistance R .
7. Sketch the h-parameter equivalent circuit of a single stage transistor amplifier operating in CB configuration.

8. What is an Oscillator?
9. What are the ideal characteristics of OP-AMP?
10. State the Barkhausen conditions for oscillations.

PART B — (5 × 16 = 80 marks)

11. (a) (i) Use Norton's theorem to find V_0 in the circuit in Fig. 1.

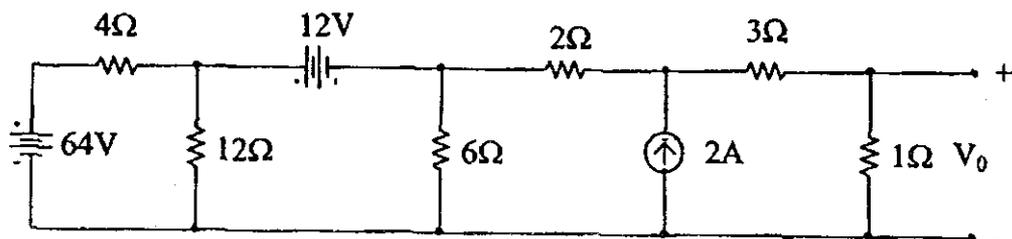


Fig. 1 Qn 11(a) (i)

- (ii) Using star-delta transformation, find the current through $4.5\text{ k}\Omega$ resistor in Fig. 2.

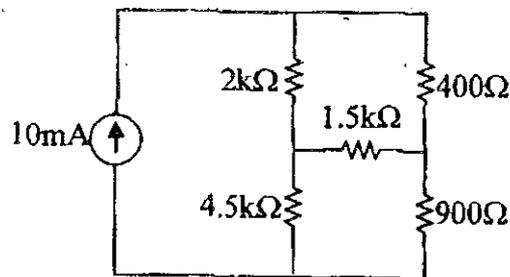


Fig. 2 Qn 11(a) (ii)

Or

- (b) (i) Determine the ABCD parameters for the network in Fig. 3.

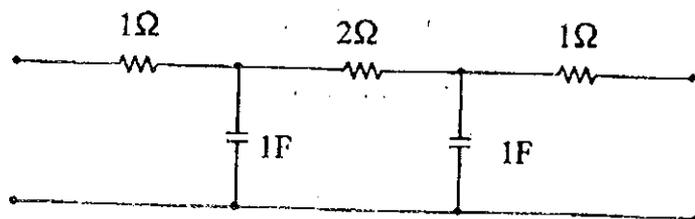


Fig. 3 Qn 11(b) (i)

- (ii) Determine the Z parameter for the network shown in Fig. 4.

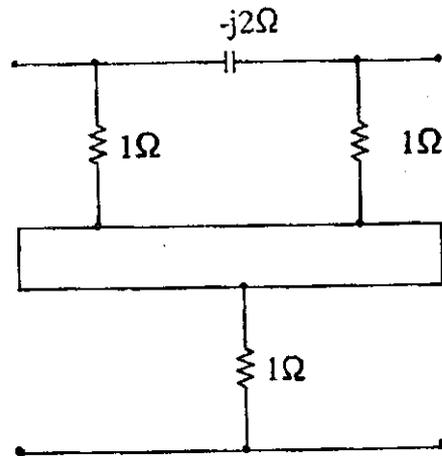


Fig. 4 Qn 11(b) (ii)

12. (a) (i) With a neat sketch, describe the action of a PN junction diode under forward and reverse bias.
- (ii) Explain the mechanism of biasing of a transistor by collector feedback bias.

Or

- (b) (i) With a neat sketch, explain the input and output characteristics of junction transistor in CE configuration.
- (ii) Explain how the constructional feature of a MOSFET differs from that of a JFET.
13. (a) (i) With a neat sketch, explain the working of a Half Wave Rectifier (HWR) using diode.
- (ii) With a neat sketch, explain the action of a clipper and a clamper circuit.

Or

- (b) (i) With a neat sketch, explain the equivalent circuit of an ideal zener diode in the breakdown region.
- (ii) Explain how a zener diode maintains constant voltage across the load.

14. (a) (i) Give the equivalent circuit of a typical small signal amplifier. Obtain expressions for voltage gain and current gain.
- (ii) Discuss the effect of negative feedback on gain, bandwidth and distortion.

Or

- (b) (i) Derive an expression for frequency of oscillation of a Colpitts Oscillator.
- (ii) Explain the operation of a Hartley oscillator.
15. (a) (i) Explain how an OP-AMP can be used as (1) an integrator and (2) a precision amplifier.
- (ii) Briefly explain the operation of a Schmitt trigger using OP-AMP and give some applications.

Or

- (b) (i) With a neat sketch, explain the RC phase shift oscillator and obtain an expression for frequency of oscillation.
- (ii) Explain the working of a Monostable multivibrator circuit with a neat sketch. Also draw its output waveforms.